

PJQ4401P-AU

30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-50 A

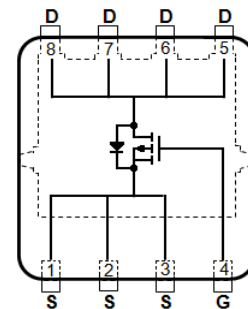
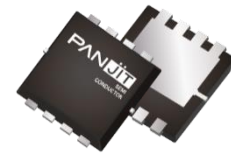
Features

- $R_{DS(ON)}$, $V_{GS}@-10V, I_D@-10A < 8.5m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V, I_D@-8A < 14m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 Standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	+20	
Continuous Drain Current	I_D	$T_C=25^\circ\text{C}$	A
		$T_C=100^\circ\text{C}$	
Pulsed Drain Current ^(Note 1)	I_{DM}	-200	
Power Dissipation	P_D	$T_C=25^\circ\text{C}$	60
		$T_C=100^\circ\text{C}$	24
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	-10
		$T_A=70^\circ\text{C}$	-8
Power Dissipation	P_D	$T_A=25^\circ\text{C}$	2.0
Power Dissipation		$T_A=70^\circ\text{C}$	1.3
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{\theta JC}$	2.1
	Junction to Ambient	$R_{\theta JA}$	62.5

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.5	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	7.1	8.5	mΩ
		V _{GS} =-4.5V, I _D =-8A	-	10	14	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 6)						
Total Gate Charge	Q _g	V _{DS} =-15V, I _D =-10A, V _{GS} =-4.5V ^(Note 1,2)	-	27	-	nC
Gate-Source Charge	Q _{gs}		-	8.4	-	
Gate-Drain Charge	Q _{gd}		-	8.7	-	
Input Capacitance	C _{iss}	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	3228	-	pF
Output Capacitance	C _{oss}		-	396	-	
Reverse Transfer Capacitance	C _{rss}		-	254	-	
Turn-On Delay Time	t _{d(on)}	V _{DS} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω (Note 1,2)	-	10	-	ns
Turn-On Rise Time	t _r		-	13	-	
Turn-Off Delay Time	t _{d(off)}		-	111	-	
Turn-Off Fall Time	t _f		-	51	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-50	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.7	-1	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

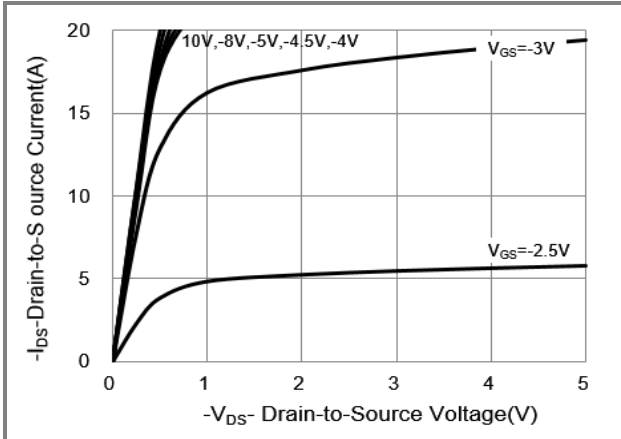


Fig.1 On-Region Characteristics

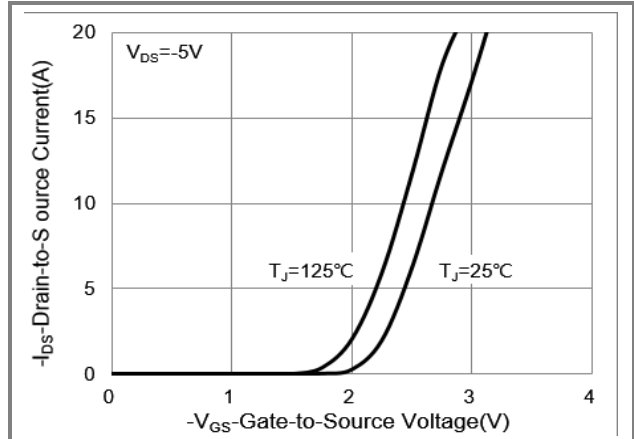


Fig.2 Transfer Characteristics

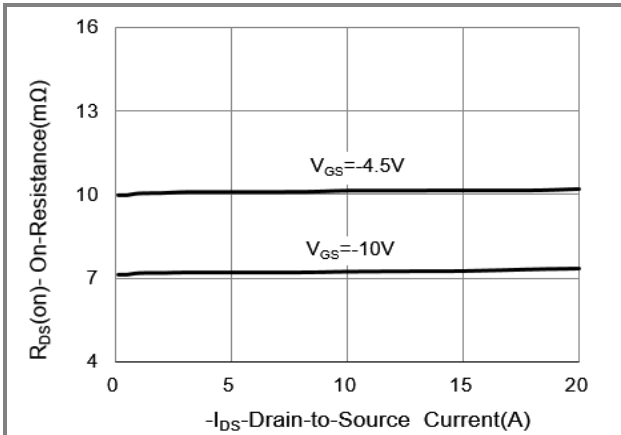


Fig.3 On-Resistance vs. Drain Current

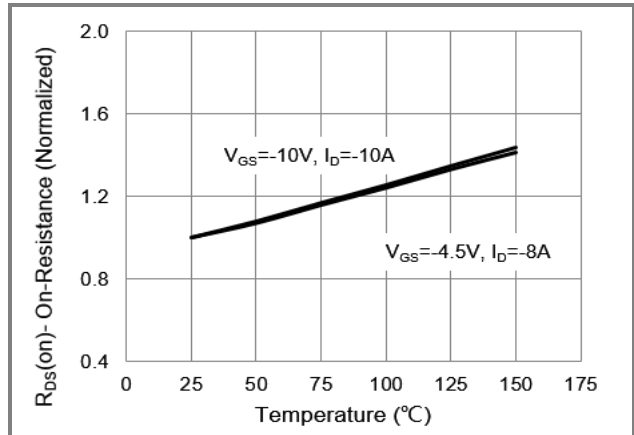


Fig.4 On-Resistance vs. Junction temperature

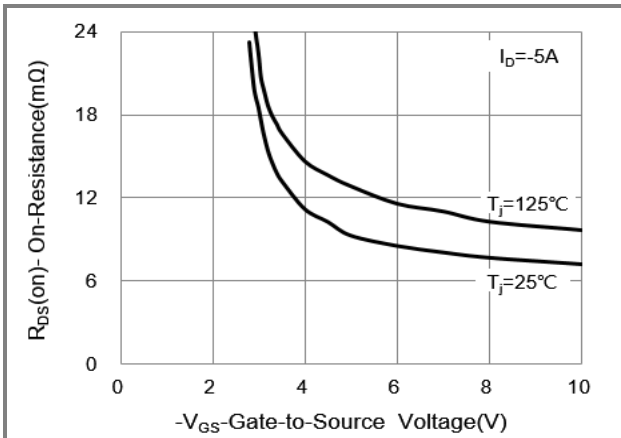


Fig.5 On-Resistance Variation with V_GS.

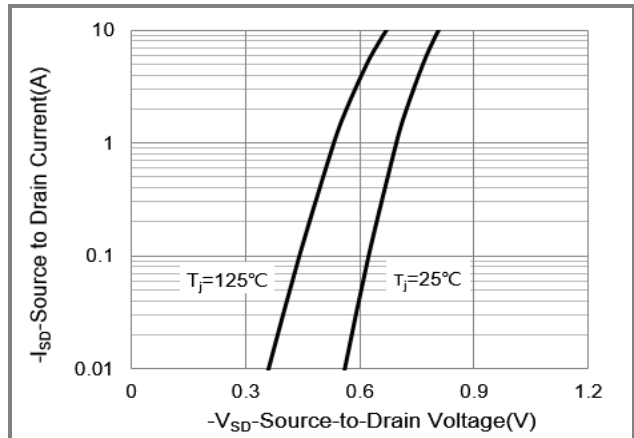


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

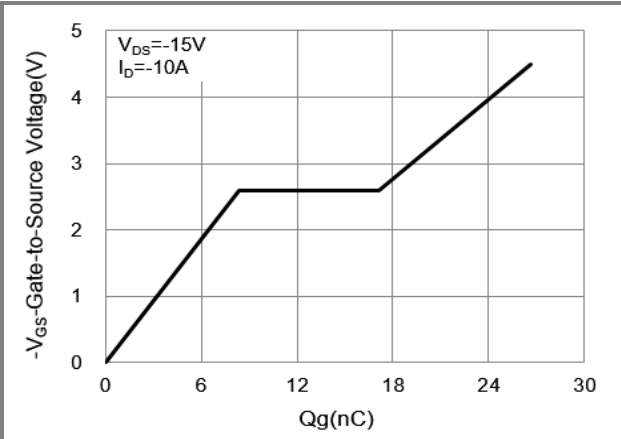


Fig.7 Gate-Charge Characteristics

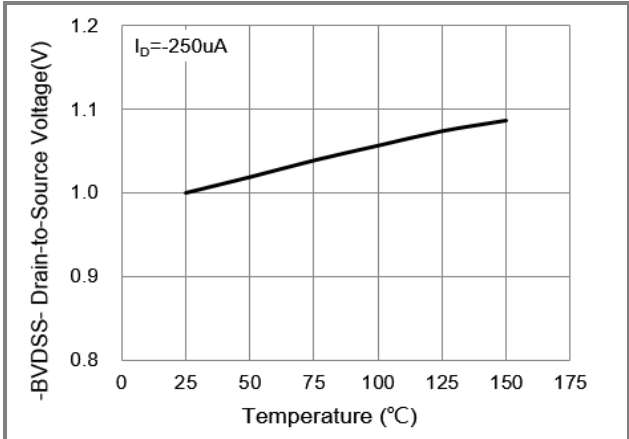


Fig.8 Breakdown Voltage Variation vs. Temperature.

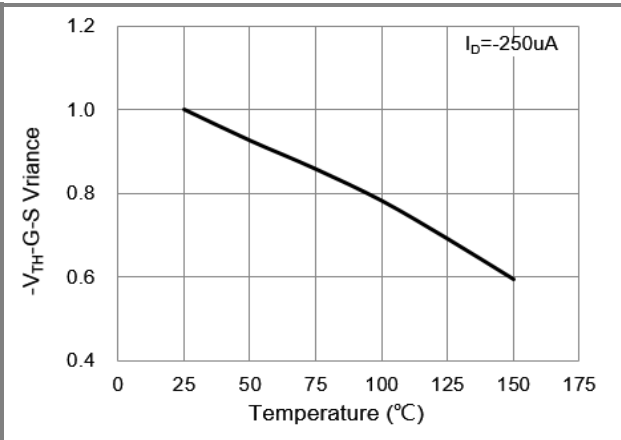


Fig.9 Threshold Voltage Variation with Temperature

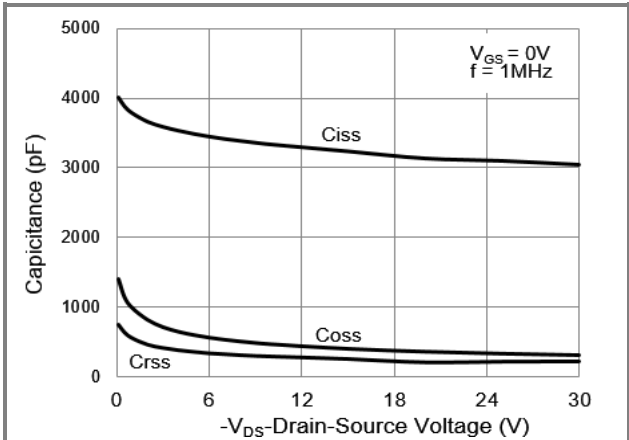


Fig.10 Capacitance vs. Drain-Source Voltage

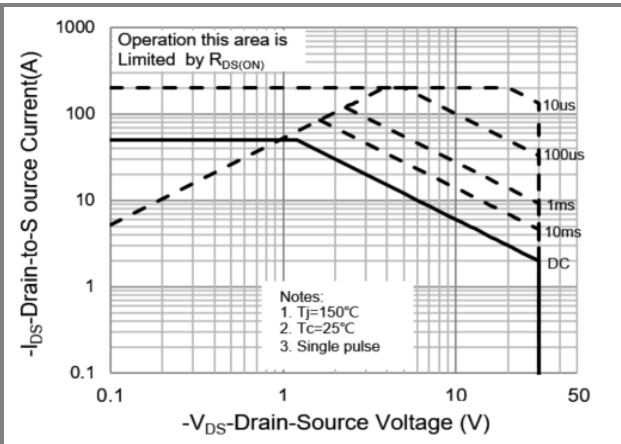


Fig.11 Maximum Safe Operating Area

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TYPICAL CHARACTERISTIC CURVES

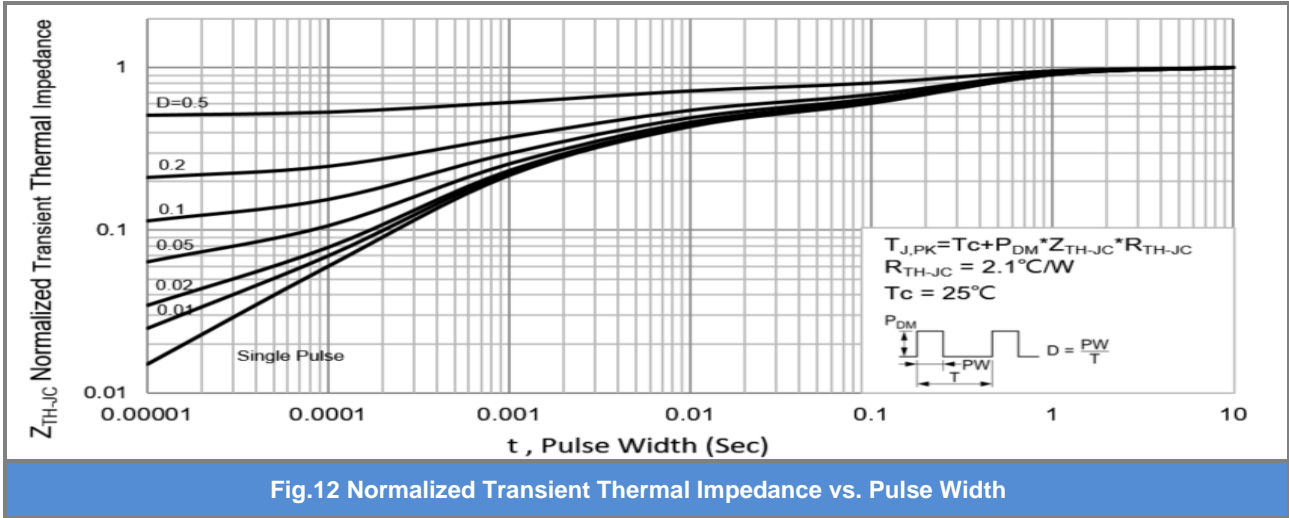


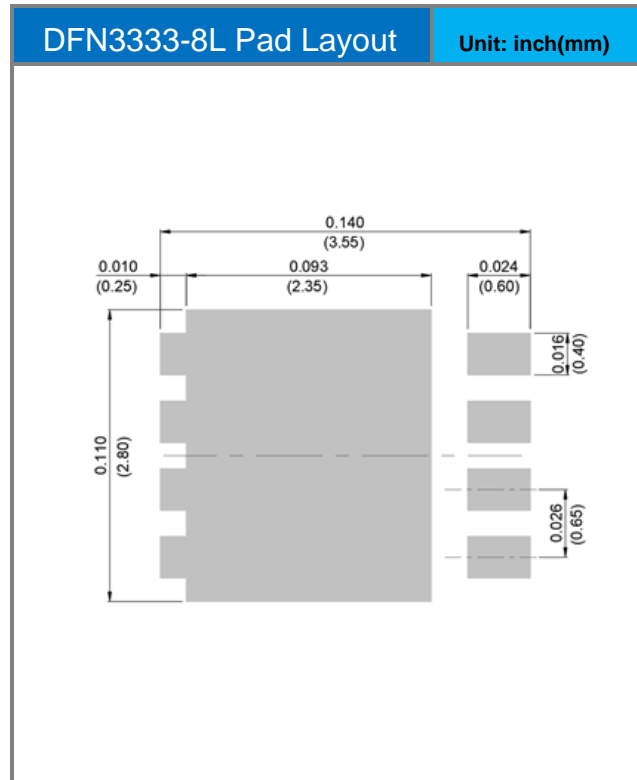
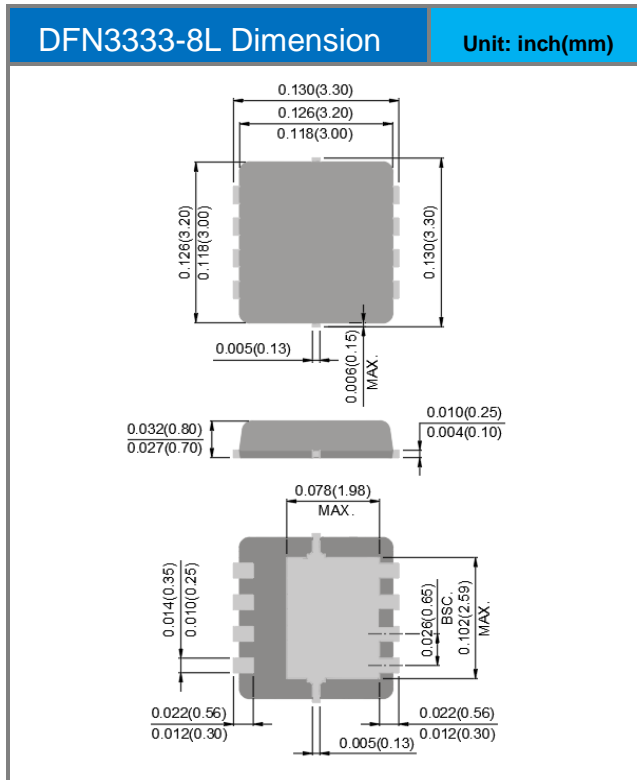
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

PJQ4401P-AU

Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4401P-AU_R2_000A1	DFN3333-8L	5K pcs / 13" reel	4401	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout



PJQ4401P-AU

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